

Features

- Trench Power LV MOSFET Technology
- Excellent Package for Heat Dissipation
- High Density Cell Design for Low $R_{DS(ON)}$
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

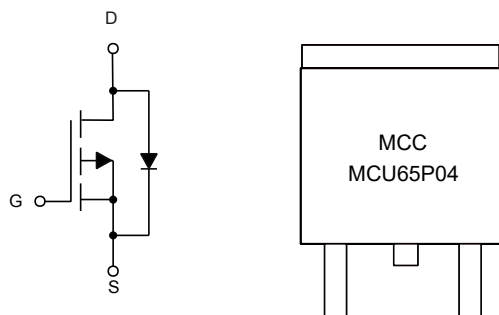
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 50°C/W Junction to Ambient (Note2)
- Thermal Resistance: 1.3°C/W Junction to Case

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V _{DS}	-40	V
Gate-Source Voltlage		V _{GS}	±20	V
Continuous Drain Current	T _C =25°C	I _D	-65	A
	T _C =100°C		-41	
Pulsed Drain Current ^{†(Note3)}		I _{DM}	-220	A
Total Power Dissipation ^(Note4)		P _D	96	W
Single Pulsed Avalanche Energy ^{†(Note5)}		E _{AS}	132	mJ

Note:

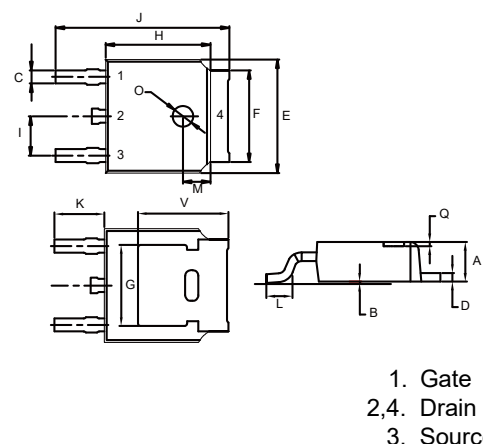
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-case thermal resistance.
5. $T_J=25^\circ\text{C}$, $V_{DD}= -40\text{V}$, $V_{GS}= -10\text{V}$, $L= 0.5\text{mH}$

Internal Structure and Marking Code



P-CHANNEL MOSFET

DPAK(TO-252)



DIMENSIONS					
DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.087	0.094	2.20	2.40	
B	0.000	0.005	0.00	0.13	
C	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
E	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
H	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
M	0.063		1.60		TYP.
O	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-40			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-40V, V _{GS} =0V			-1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.6	-2.5	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-20A		10.5	14	mΩ
Gate Resistance	R _g	f=1MHz		6		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				-65	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-20A			-1.3	V
Reverse Recovery Time	t _{rr}	I _S =-14A, dI _F /dt=100A/μs		28		ns
Reverse Recovery Charge	Q _{rr}			21		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} =-20V, V _{GS} =0V, f=1MHz		3354		pF
Output Capacitance	C _{oss}			340		
Reverse Transfer Capacitance	C _{rss}			253		
Total Gate Charge	Q _g	V _{DS} =-20V, V _{GS} =-10V, I _D =-14A		59.1		nC
Gate-Source Charge	Q _{gs}			9		
Gate-Drain Charge	Q _{gd}			11		
Turn-On Delay Time	t _{d(on)}	V _{DS} =-20V, V _{GEN} =-10V, R _G =6Ω, I _{DS} =-1A		11.2		ns
Turn-On Rise Time	t _r			10		
Turn-Off Delay Time	t _{d(off)}			149		
Turn-Off Fall Time	t _f			56		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

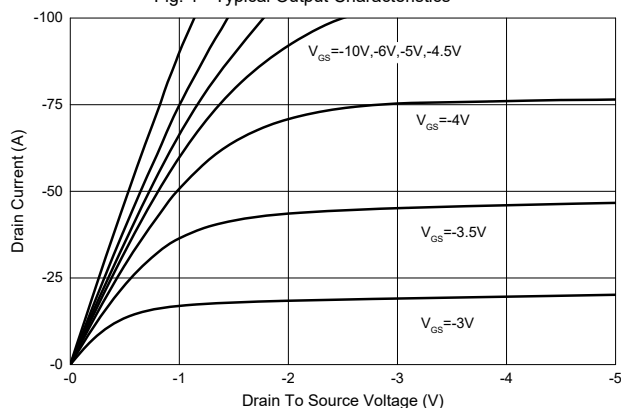


Fig. 2 - Transfer Characteristics

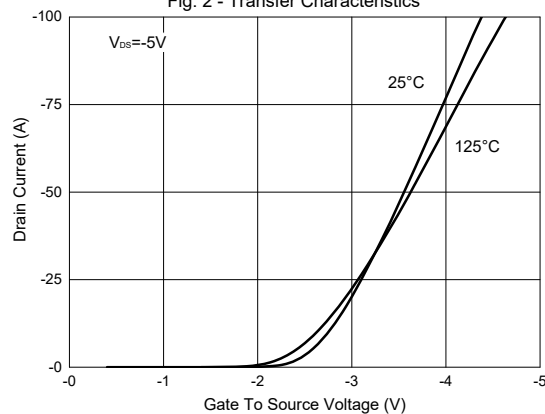


Fig. 3 - $R_{DS(ON)} - I_D$

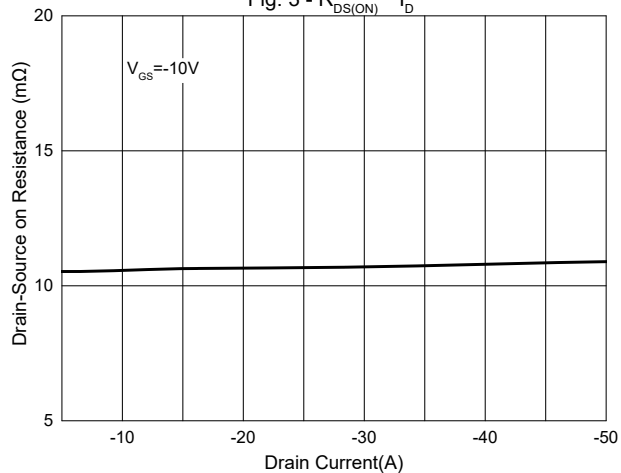


Fig. 4 - $R_{DS(ON)} - V_{GS}$

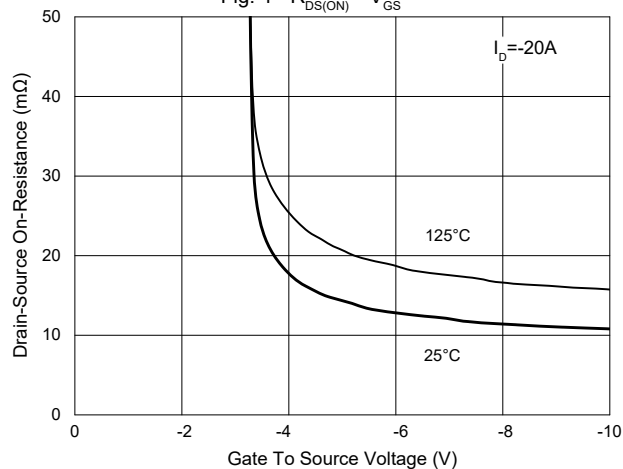


Fig. 5 - Normalized On Resistance Characteristics

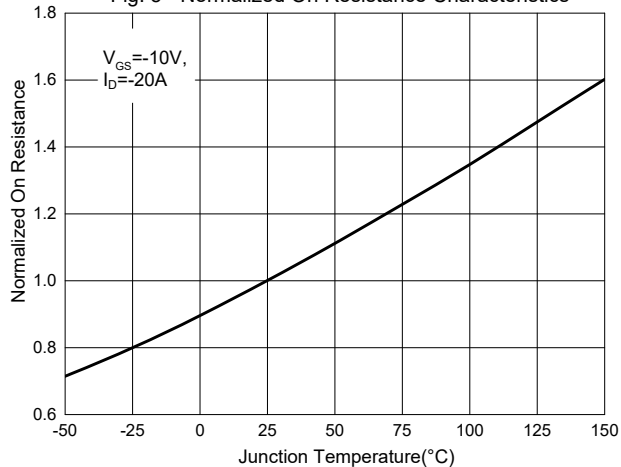
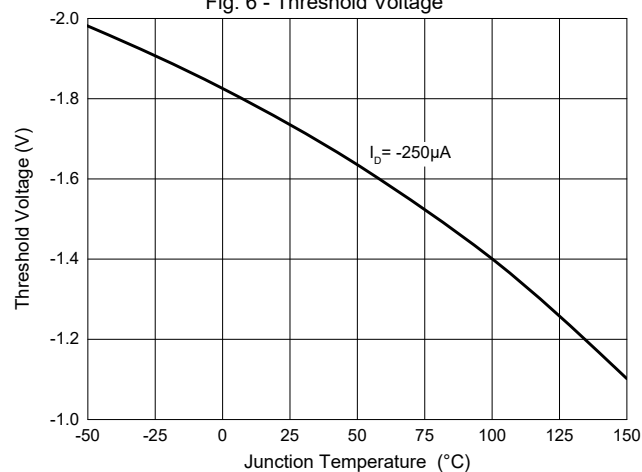


Fig. 6 - Threshold Voltage



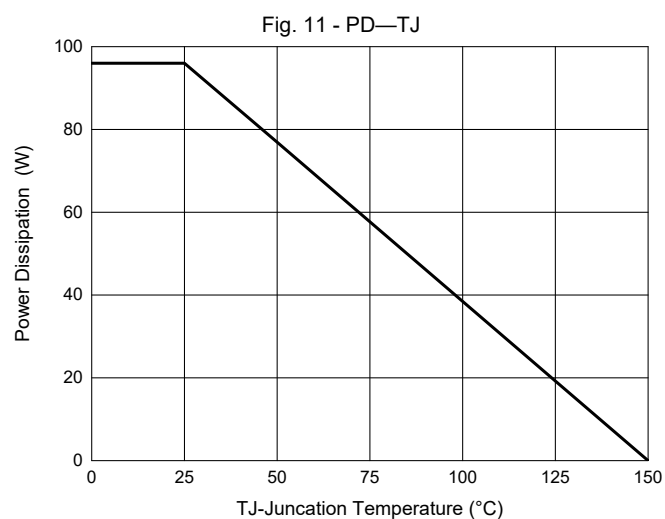
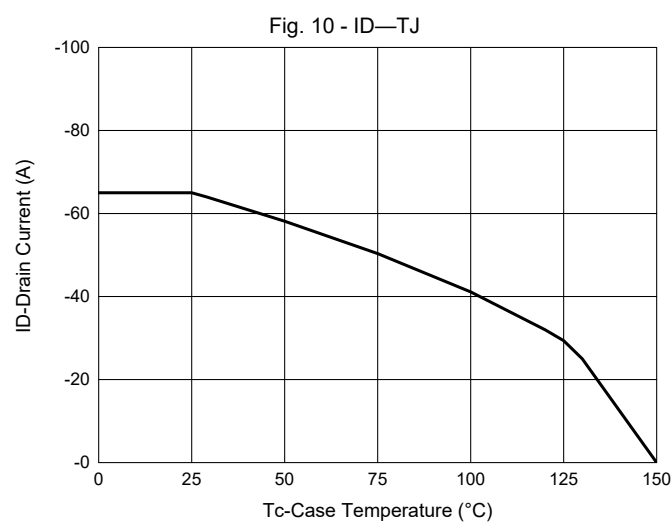
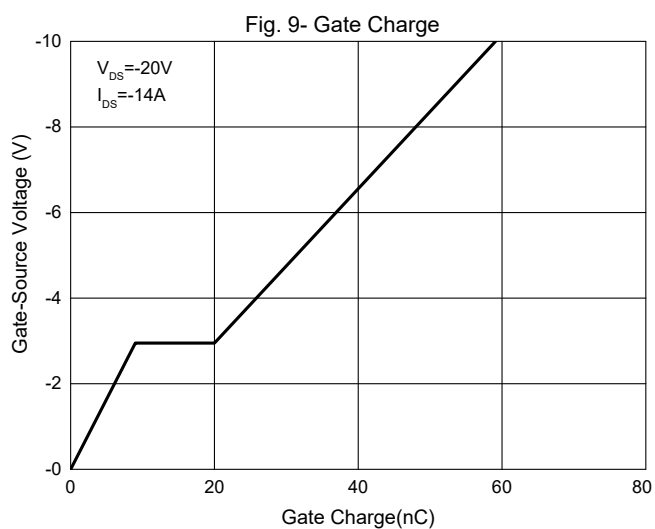
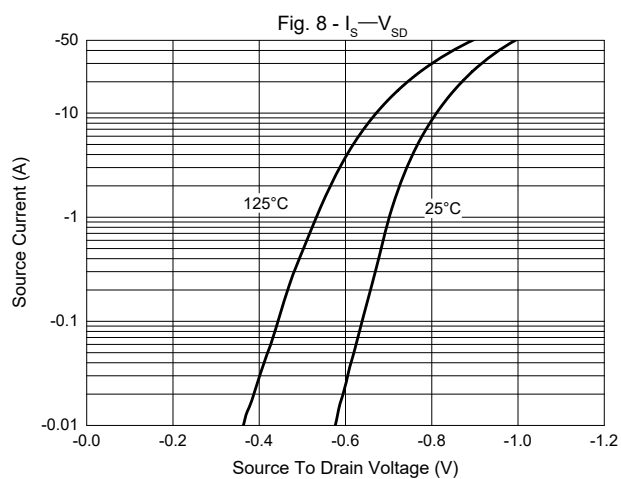
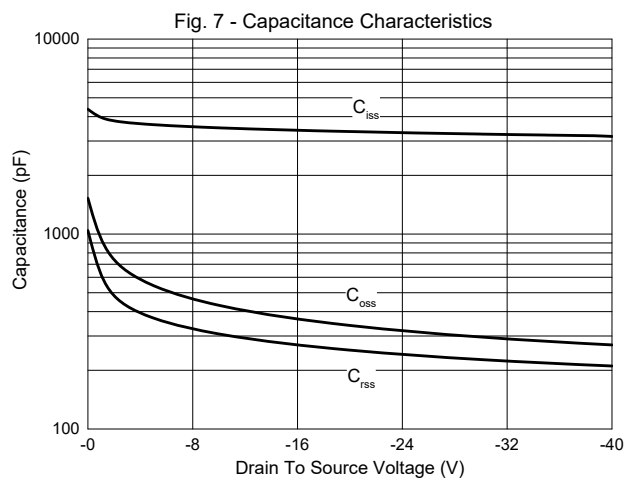


Fig. 12 - Safe Operation Area

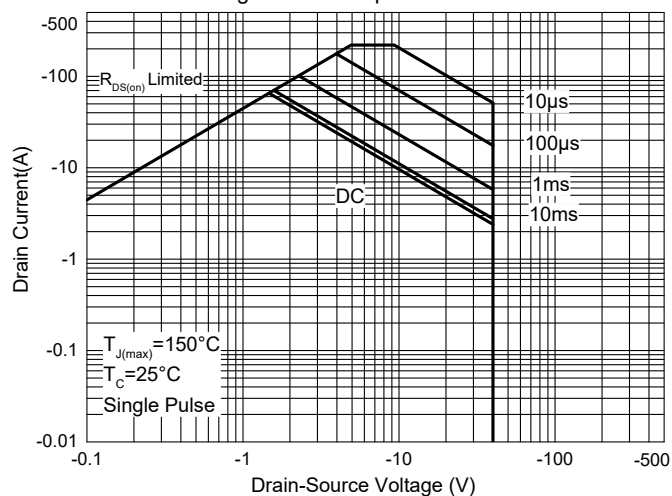
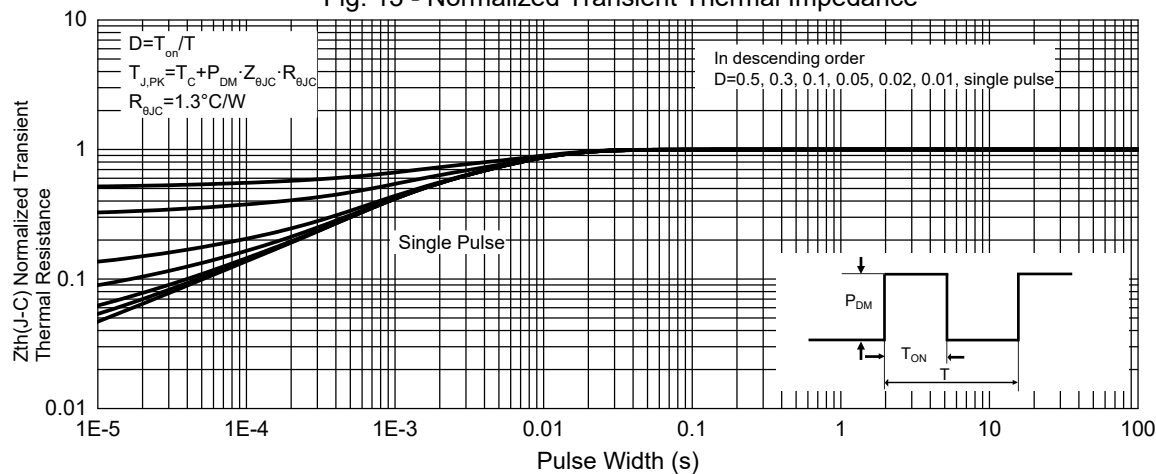


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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